

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







# **HEF4104B**

# Quad low-to-high voltage translator with 3-state outputs

Rev. 9 — 29 March 2016

**Product data sheet** 

## 1. General description

The HEF4104B is a quad low voltage-to-high voltage translator with 3-state outputs. It provides the capability of interfacing low voltage circuits to high voltage circuits. For example low voltage Local Oxidation Complementary MOS (LOCMOS) and Transistor-Transistor Logic (TTL) to high voltage LOCMOS. It has four data inputs (A0 to A3), an active HIGH output enable input (OE), four data outputs (B0 to B3) and their complements ( $\overline{B}0$  to  $\overline{B}3$ ).

With OE = HIGH, the outputs B0 to B3 and  $\overline{B}0$  to  $\overline{B}3$  are in the low impedance ON-state, either HIGH or LOW as determined by the inputs A0 to A3. With OE = LOW, the outputs B0 to B3 and  $\overline{B}0$  to  $\overline{B}3$  are in the high-impedance OFF-state.

It uses a common negative supply  $(V_{SS})$  and separate positive supplies for the inputs  $(V_{DD(A)})$  and the outputs  $(V_{DD(B)})$ .  $V_{DD(A)}$  must always be less than or equal to  $V_{DD(B)}$ , even during power turn-on and turn-off. For the permissible operating range of  $V_{DD(A)}$  and  $V_{DD(B)}$  see Figure 4.

Each input protection circuit is terminated between  $V_{DD(B)}$  and  $V_{SS}$ . This allows the input signals to be driven from any potential between  $V_{DD(B)}$  and  $V_{SS}$ , without regard to current limiting. When driving from potentials greater than  $V_{DD(B)}$  or less than  $V_{SS}$ , the current at each input must be limited to 10 mA.

It operates over a recommended  $V_{DD}$  power supply range of 3 V to 15 V referenced to  $V_{SS}$  (usually ground). Unused inputs must be connected to  $V_{DD}$ ,  $V_{SS}$ , or another input.

#### 2. Features and benefits

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Inputs and outputs are protected against electrostatic effects
- Specified from –40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

## 3. Ordering information

#### Table 1. Ordering information

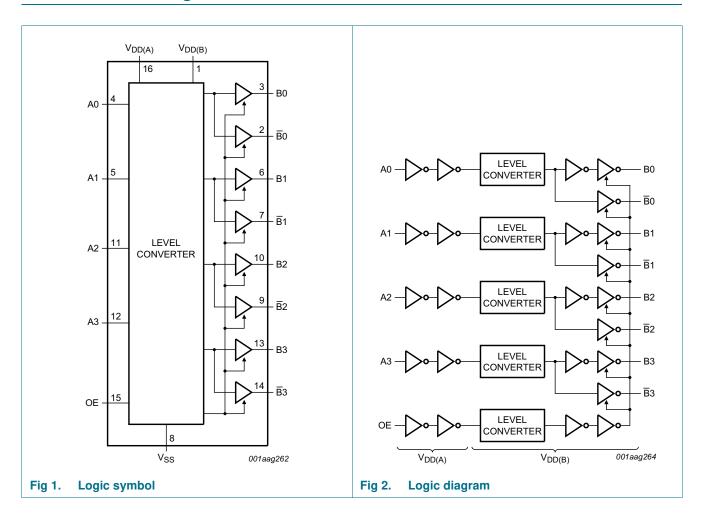
All types operate from  $-40 \,^{\circ}\text{C}$  to  $+85 \,^{\circ}\text{C}$ .

| Type number | Package |  |          |
|-------------|---------|--|----------|
|             | Name    | Description  | Version  |
| HEF4104BT   | SO16    | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 |



### Quad low-to-high voltage translator with 3-state outputs

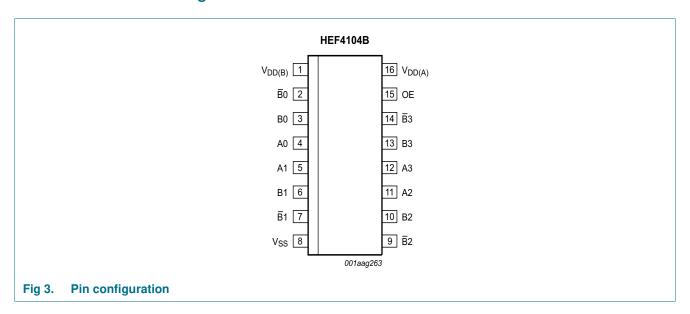
# 4. Functional diagram



### Quad low-to-high voltage translator with 3-state outputs

# 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

| Symbol          | Pin          | Description                          |
|-----------------|--------------|--------------------------------------|
| $V_{DD(B)}$     | 1            | supply voltage port B                |
| B0 to B3        | 2, 7, 9, 14  | complementary data output            |
| B0 to B3        | 3, 6, 10, 13 | data output                          |
| A0 to A3        | 4, 5, 11, 12 | data input                           |
| V <sub>SS</sub> | 8            | common negative supply voltage (0 V) |
| OE              | 15           | output enable input                  |
| $V_{DD(A)}$     | 16           | supply voltage port A                |

# 6. Functional description

Table 3. Function table[1]

| Control | Output |    |  |  |  |
|---------|--------|----|--|--|--|
| OE      | Bn     | Bn |  |  |  |
| Н       | An     | Ān |  |  |  |
| L       | Z      | Z  |  |  |  |

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

### Quad low-to-high voltage translator with 3-state outputs

# 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to  $V_{SS} = 0 \text{ V}$  (ground).

|                  |                         | <i>y</i> , , , , , , , , , , , , , , , , , , ,                      |     |                 | 00 10             | ,    |
|------------------|-------------------------|---|-----|-----------------|-------------------|------|
| Symbol           | Parameter               | Conditions  |     | Min             | Max               | Unit |
| $V_{DD(A)}$      | supply voltage A        | port A; $V_{DD(A)} \le V_{DD(B)}$                                   |     | -0.5            | +18               | V    |
| $V_{DD(B)}$      | supply voltage B        | port B; $V_{DD(B)} \ge V_{DD(A)}$                                   |     | -0.5            | +18               | V    |
| I <sub>IK</sub>  | input clamping current  | $V_{I} < -0.5 \text{ V or } V_{I} > V_{DD(A)} + 0.5 \text{ V}$      |     | -               | ±10               | mA   |
| VI               | input voltage           |   |     | -0.5            | $V_{DD(A)} + 0.5$ | V    |
| lok              | output clamping current | $V_O < -0.5 \text{ V or } V_O > V_{DD(B)} + 0.5 \text{ V}$          |     | -               | ±10               | mA   |
| I <sub>I/O</sub> | input/output current    |   |     | -               | ±10               | mA   |
| I <sub>DD</sub>  | supply current          |   | [1] | -               | 50                | mA   |
| T <sub>stg</sub> | storage temperature     |   |     | <del>-</del> 65 | +150              | °C   |
| T <sub>amb</sub> | ambient temperature     |   |     | -40             | +85               | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40  ^{\circ}\text{C} \text{ to } +85  ^{\circ}\text{C}$ |     |                 |                   |      |
|                  |                         | SO16  | [2] | -               | 500               | mW   |
| Р                | power dissipation       | per output  |     | -               | 100               | mW   |
|                  |                         |   |     |                 |                   |      |

<sup>[1]</sup>  $I_{DD}$  is the combined current of  $I_{DD(A)}$  and  $I_{DD(B)}$ .

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol              | Parameter                           | Conditions                 | Min              | Тур | Max              | Unit |
|---------------------|-------------------------------------|----------------------------|------------------|-----|------------------|------|
| $V_{DD(A)}$         | supply voltage A                    |                            | 3                | -   | $\leq V_{DD(B)}$ | V    |
| $V_{DD(B)}$         | supply voltage B                    |                            | $\geq V_{DD(A)}$ | -   | 15               | V    |
| VI                  | input voltage                       |                            | 0                | -   | $V_{DD(A)}$      | V    |
| T <sub>amb</sub>    | ambient temperature                 | in free air                | -40              | -   | +85              | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | V <sub>DD(A)</sub> = 5 V   | -                | -   | 3.75             | μs/V |
|                     |                                     | $V_{DD(A)} = 10 \text{ V}$ | -                | -   | 0.5              | μs/V |
|                     |                                     | $V_{DD(A)} = 15 \text{ V}$ | -                | -   | 0.08             | μs/V |

<sup>[2]</sup> For SO16 packages: above T<sub>amb</sub> = 70 °C, P<sub>tot</sub> derates linearly at 8 mW/K.

### Quad low-to-high voltage translator with 3-state outputs

## 9. Static characteristics

Table 6. Static characteristics

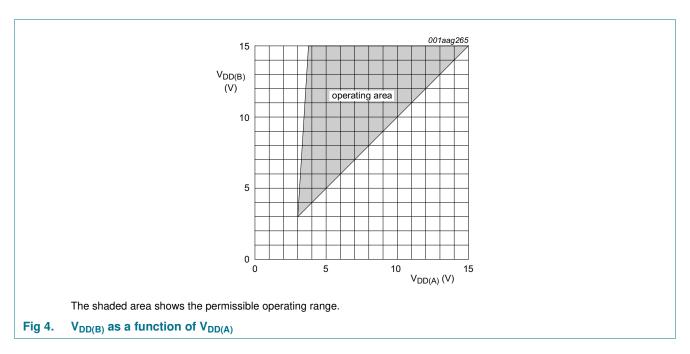
 $V_{DD(A)} = V_{DD(B)}$ ;  $V_{SS} = 0$  V;  $V_{I} = V_{SS}$  or  $V_{DD(A)}$ ; unless otherwise specified.

| Symbol          | Parameter                 | Conditions   | V <sub>DD</sub> [1] | T <sub>amb</sub> = | –40 °C | T <sub>amb</sub> = | +25 °C | T <sub>amb</sub> = | +85 °C | Unit |
|-----------------|---------------------------|--|---------------------|--------------------|--------|--------------------|--------|--------------------|--------|------|
|                 |                           |  |                     | Min                | Max    | Min                | Max    | Min                | Max    |      |
| V <sub>IH</sub> | HIGH-level                | $ I_{O}  < 1 \mu A$                                | 5 V                 | 3.5                | -      | 3.5                | -      | 3.5                | -      | V    |
|                 | input voltage             |  | 10 V                | 7.0                | -      | 7.0                | -      | 7.0                | -      | V    |
|                 |                           |  | 15 V                | 11.0               | -      | 11.0               | -      | 11.0               | -      | V    |
| $V_{IL}$        | LOW-level                 | $ I_{O}  < 1 \mu A$                                | 5 V                 | -                  | 1.5    | -                  | 1.5    | -                  | 1.5    | V    |
|                 | input voltage             |  | 10 V                | -                  | 3.0    | -                  | 3.0    | -                  | 3.0    | V    |
|                 |                           |  | 15 V                | -                  | 4.0    | -                  | 4.0    | -                  | 4.0    | V    |
| $V_{OH}$        | HIGH-level                | $ I_{O}  < 1 \mu A$                                | 5 V                 | 4.95               | -      | 4.95               | -      | 4.95               | -      | V    |
|                 | output voltage            |  | 10 V                | 9.95               | -      | 9.95               | -      | 9.95               | -      | V    |
|                 |                           |  | 15 V                | 14.95              | -      | 14.95              | -      | 14.95              | -      | ٧    |
| $V_{OL}$        | LOW-level                 | $ I_0  < 1 \mu A$                                  | 5 V                 | -                  | 0.05   | -                  | 0.05   | -                  | 0.05   | V    |
|                 | output voltage            |  | 10 V                | -                  | 0.05   | -                  | 0.05   | -                  | 0.05   | V    |
|                 |                           |  | 15 V                | -                  | 0.05   | -                  | 0.05   | -                  | 0.05   | V    |
| I <sub>OH</sub> | HIGH-level output current | V <sub>O</sub> = 2.5 V                             | 5 V                 | -                  | -1.7   | -                  | -1.4   | -                  | -1.1   | mA   |
|                 |                           | V <sub>O</sub> = 4.6 V                             | 5 V                 | -                  | -0.52  | -                  | -0.44  | -                  | -0.36  | mA   |
|                 |                           | V <sub>O</sub> = 9.5 V                             | 10 V                | -                  | -1.3   | -                  | -1.1   | -                  | -0.9   | mA   |
|                 |                           | V <sub>O</sub> = 13.5 V                            | 15 V                | -                  | -3.6   | -                  | -3.0   | -                  | -2.4   | mA   |
| I <sub>OL</sub> | LOW-level                 | V <sub>O</sub> = 0.4 V                             | 5 V                 | 0.52               | -      | 0.44               | -      | 0.36               | -      | mA   |
|                 | output current            | $V_{O} = 0.5 \text{ V}$                            | 10 V                | 1.3                | -      | 1.1                | -      | 0.9                | -      | mA   |
|                 |                           | V <sub>O</sub> = 1.5 V                             | 15 V                | 3.6                | -      | 3.0                | -      | 2.4                | -      | mA   |
| I <sub>I</sub>  | input leakage current     |  | 15 V                | -                  | ±0.3   | -                  | ±0.3   | -                  | ±1.0   | μΑ   |
| $I_{DD}$        | supply current            | all valid input                                    | 5 V 🔼               | -                  | 20     | -                  | 20     | -                  | 150    | μΑ   |
|                 |                           | combinations;                                      | 10 V                | -                  | 40     | -                  | 40     | -                  | 300    | μΑ   |
|                 |                           | I <sub>O</sub> = 0 A                               | 15 V                | -                  | 80     | -                  | 80     | -                  | 600    | μΑ   |
| l <sub>OZ</sub> | OFF-state output current  | HIGH level;<br>V <sub>O</sub> = V <sub>DD(B)</sub> | 15 V                | -                  | 1.6    | -                  | 1.6    | -                  | 12.0   | μΑ   |
|                 |                           | LOW level;<br>V <sub>O</sub> = V <sub>SS</sub>     | 15 V                | -                  | -1.6   | -                  | -1.6   | -                  | -12.0  | μΑ   |
| Cı              | input capacitance         | digital inputs                                     | -                   | -                  | -      | -                  | 7.5    | -                  | -      | pF   |

<sup>[1]</sup>  $V_{DD}$  is the same as  $V_{DD(A)}$  and  $V_{DD(B)}$ .

<sup>[2]</sup>  $I_{DD}$  is the combined current of  $I_{DD(A)}$  and  $I_{DD(B)}$ .

### Quad low-to-high voltage translator with 3-state outputs



# 10. Dynamic characteristics

Table 7. Dynamic characteristics

 $T_{amb}$  = 25 °C; for test circuit see <u>Figure 7</u>; unless otherwise specified.

| Symbol           | Parameter                          | Conditions                             | Extrapolation formula[1]            | Min | Тур | Max | Unit |
|------------------|------------------------------------|--|-------------------------------------|-----|-----|-----|------|
| t <sub>PHL</sub> | HIGH to LOW                        | An to Bn, Bn; see Figure 5             |                                     |     |     |     |      |
|                  | propagation delay                  | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  | 143 ns + (0.55 ns/pF)C <sub>L</sub> | -   | 170 | 340 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ | 69 ns + (0.23 ns/pF)C <sub>L</sub>  | -   | 80  | 160 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ | 57 ns + (0.16 ns/pF)C <sub>L</sub>  | -   | 65  | 135 | ns   |
| t <sub>PLH</sub> | LOW to HIGH                        | An to Bn, Bn; see Figure 5             |                                     |     |     |     |      |
|                  | propagation delay                  | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  | 143 ns + (0.55 ns/pF)C <sub>L</sub> | -   | 170 | 340 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ | 69 ns + (0.23 ns/pF)C <sub>L</sub>  | -   | 80  | 160 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ | 62 ns + (0.16 ns/pF)C <sub>L</sub>  | -   | 70  | 140 | ns   |
| t <sub>THL</sub> | HIGH to LOW output transition time | Bn or Bn; see Figure 6                 |                                     |     |     |     |      |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  | 10 ns + (1.00 ns/pF)C <sub>L</sub>  | -   | 60  | 120 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ | 9 ns + (0.42 ns/pF)C <sub>L</sub>   | -   | 30  | 60  | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ | 6 ns + (0.28 ns/pF)C <sub>L</sub>   | -   | 20  | 40  | ns   |
| t <sub>TLH</sub> | LOW to HIGH output                 | Bn or Bn; see Figure 6                 |                                     |     |     |     |      |
|                  | transition time                    | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  | 10 ns + (1.00 ns/pF)C <sub>L</sub>  | -   | 60  | 120 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ | 9 ns + (0.42 ns/pF)C <sub>L</sub>   | -   | 30  | 60  | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ | 6 ns + (0.28 ns/pF)C <sub>L</sub>   | -   | 20  | 40  | ns   |
| t <sub>PHZ</sub> | HIGH to OFF-state                  | OE to Bn, Bn; see Figure 6             |                                     |     |     |     |      |
|                  | propagation delay                  | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  |                                     | -   | 70  | 135 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ |                                     | -   | 55  | 110 | ns   |
|                  |                                    | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ |                                     | -   | 60  | 120 | ns   |

### Quad low-to-high voltage translator with 3-state outputs

 Table 7.
 Dynamic characteristics ...continued

T<sub>amb</sub> = 25 °C; for test circuit see <u>Figure 7</u>; unless otherwise specified.

| Symbol                            | Parameter         | Conditions                             | Extrapolation formula[1] | Min | Тур | Max | Unit |
|-----------------------------------|-------------------|--|--------------------------|-----|-----|-----|------|
| t <sub>PLZ</sub> LOW to OFF-state |                   | OE to Bn, Bn; see Figure 6             |                          |     |     |     |      |
|                                   | propagation delay | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  |                          | -   | 70  | 135 | ns   |
|                                   |                   | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ |                          | -   | 55  | 105 | ns   |
|                                   |                   | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ |                          | -   | 55  | 110 | ns   |
| t <sub>PZH</sub>                  | OFF-state to HIGH | OE to Bn, Bn; see Figure 6             |                          |     |     |     |      |
|                                   | propagation delay | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  |                          | -   | 195 | 395 | ns   |
|                                   |                   | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ |                          | -   | 95  | 195 | ns   |
|                                   |                   | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ |                          | -   | 80  | 165 | ns   |
| t <sub>PZL</sub>                  | OFF-state to LOW  | OE to Bn, Bn; see Figure 6             |                          |     |     |     |      |
| propagatio                        | propagation delay | $V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$  |                          | -   | 195 | 395 | ns   |
|                                   |                   | $V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$ |                          | -   | 95  | 190 | ns   |
|                                   |                   | $V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$ |                          | -   | 80  | 160 | ns   |

<sup>[1]</sup> Typical value of the propagation delay and output transition time can be calculated with the extrapolation formula ( $C_L$  in pF).

### Table 8. Dynamic power dissipation

 $V_{DD(A)} = V_{DD(B)}$ ;  $V_{SS} = 0$  V;  $t_r = t_f \le 20$  ns;  $T_{amb} = 25$  °C.

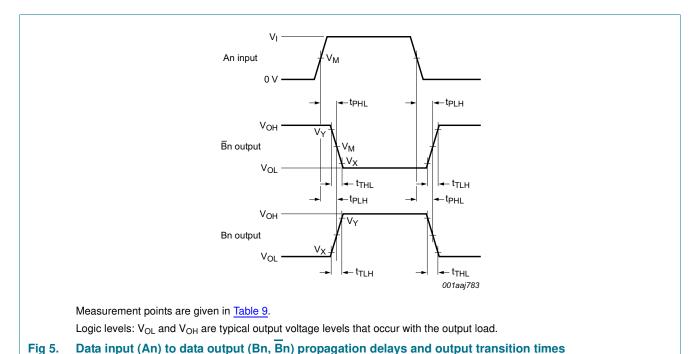
| Symbol | Parameter     | V <sub>DD</sub> [1] | Typical formula (μW)   | where   |
|--------|---------------|---------------------|--|---|
| $P_D$  | dynamic power | 5 V                 | $P_D = 3000 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$  | $f_i$ = input frequency in MHz;                       |
|        | dissipation   | 10 V                | $P_D = 12200 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$ | fo = output frequency in MHz;                         |
|        |               | 15 V                | $P_D = 31000 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$ | $C_L$ = output load capacitance in pF;                |
|        |               |                     |  | $\Sigma(f_0 \times C_L) = \text{sum of the outputs};$ |
|        |               |                     |  | $V_{DD}$ = supply voltage in V.                       |

<sup>[1]</sup>  $V_{DD}$  is the same as  $V_{DD(A)}$  and  $V_{DD(B)}$ .

**HEF4104B Nexperia** 

## Quad low-to-high voltage translator with 3-state outputs

### 11. Waveforms



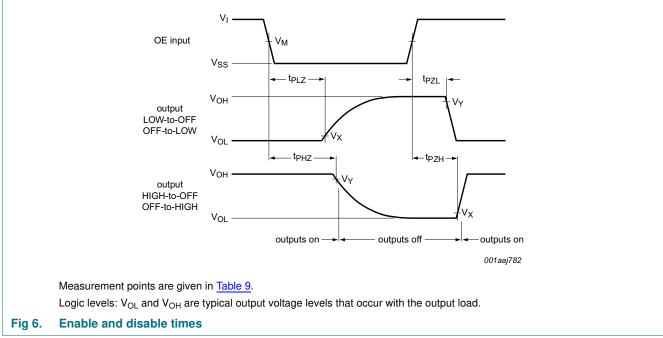


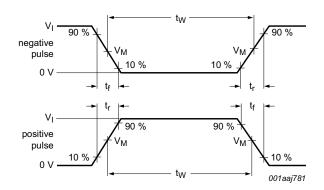
Table 9. **Measurement points** 

| Input                                 |                       | Output                |                       |                       |  |
|---------------------------------------|-----------------------|-----------------------|-----------------------|-----------------------|--|
| VI                                    | V <sub>M</sub>        | V <sub>M</sub>        | V <sub>X</sub>        | V <sub>Y</sub>        |  |
| V <sub>SS</sub> or V <sub>DD(A)</sub> | 0.5V <sub>DD(A)</sub> | 0.5V <sub>DD(B)</sub> | 0.1V <sub>DD(B)</sub> | 0.9V <sub>DD(B)</sub> |  |

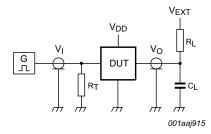
HEF4104B

All information provided in this document is subject to legal disclaimers.

### Quad low-to-high voltage translator with 3-state outputs



#### a. Input waveforms



#### b. Test circuit

Test data given in Table 10.

Definitions for test circuit:

DUT = Device Under Test.

 $C_L$  = load capacitance including jig and probe capacitance.

 $R_L$  = load resistance.

 $R_T$  = termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

Fig 7. Test circuit for measuring switching times

#### Table 10. Test data

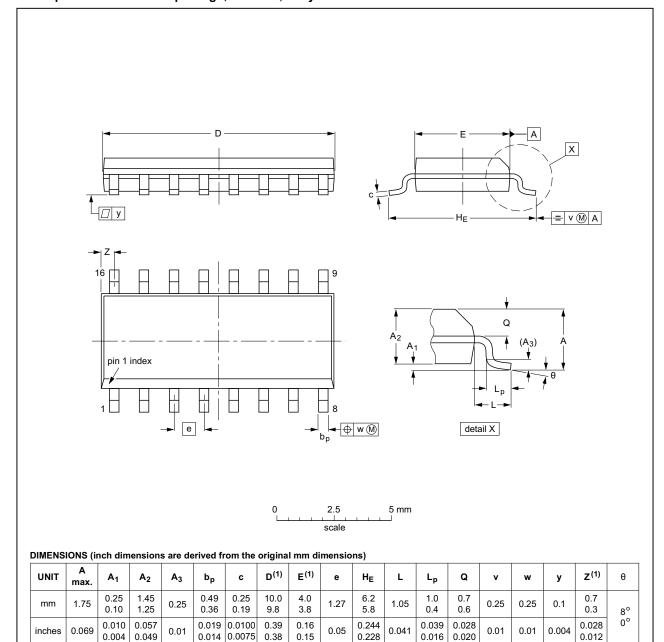
| Supplies                | Input                           | Load           | oad V <sub>EXT</sub> |                                     |                                     |                                     |
|-------------------------|---------------------------------|----------------|----------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| $V_{DD(A)} = V_{DD(B)}$ | t <sub>r</sub> , t <sub>f</sub> | R <sub>L</sub> | C <sub>L</sub>       | t <sub>PHL</sub> , t <sub>PLH</sub> | t <sub>PZL</sub> , t <sub>PLZ</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> |
| 5 V to 15 V             | ≤ 20 ns                         | 1 kΩ           | 50 pF                | open                                | $V_{DD(B)}$                         | $V_{SS}$                            |

### Quad low-to-high voltage translator with 3-state outputs

## 12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



# Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE  |        | REFER  | RENCES | EUROPEAN   | ISSUE DATE                      |
|----------|--------|--------|--------|------------|---------------------------------|
| VERSION  | IEC    | JEDEC  | JEITA  | PROJECTION | ISSUE DATE                      |
| SOT109-1 | 076E07 | MS-012 |        |            | <del>99-12-27</del><br>03-02-19 |

Fig 8. Package outline SOT109-1 (SO16)

HEF4104B

## Quad low-to-high voltage translator with 3-state outputs

# 13. Revision history

### Table 11. Revision history

| Document ID      | Release date   | Data sheet status     | Change notice | Supersedes       |  |
|------------------|--|-----------------------|---------------|------------------|--|
| HEF4104B v.9     | 20160329   | Product data sheet    | -             | HEF4104B v.8     |  |
| Modifications:   | Type number HEF4104BP (SOT38-4) removed.                           |                       |               |                  |  |
| HEF4104B v.8     | 20111111   | Product data sheet    | -             | HEF4104B v.7     |  |
| Modifications:   | Section Applications removed                                       |                       |               |                  |  |
|                  | <u>Table 6</u> : I <sub>OH</sub> minimum values changed to maximum |                       |               |                  |  |
| HEF4104B v.7     | 20091216   | Product data sheet    | -             | HEF4104B v.6     |  |
| HEF4104B v.6     | 20091102   | Product data sheet    | -             | HEF4104B v.5     |  |
| HEF4104B v.5     | 20090728   | Product data sheet    | -             | HEF4104B v.4     |  |
| HEF4104B v.4     | 20090305   | Product data sheet    | -             | HEF4104B_CNV v.3 |  |
| HEF4104B_CNV v.3 | 19950101   | Product specification | -             | HEF4104B_CNV v.2 |  |
| HEF4104B_CNV v.2 | 19950101   | Product specification | -             | -                |  |

### Quad low-to-high voltage translator with 3-state outputs

## 14. Legal information

#### 14.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

#### 14.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 14.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nexperia.com/profile/terms">http://www.nexperia.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

HEF4104B

All information provided in this document is subject to legal disclaimers.

#### Quad low-to-high voltage translator with 3-state outputs

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### 14.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

### 15. Contact information

For more information, please visit: http://www.nexperia.com

For sales office addresses, please send an email to: salesaddresses@nexperia.com

HEF4104B

## Quad low-to-high voltage translator with 3-state outputs

## 16. Contents

**Nexperia** 

| 1          | General description              | 1 |
|------------|----------------------------------|---|
| 2          | Features and benefits            | 1 |
| 3          | Ordering information             | 1 |
| 4          | Functional diagram               | 2 |
| 5          | Pinning information              | 3 |
| 5.1<br>5.2 | Pinning                          |   |
| 6          | Functional description           |   |
| 7          | Limiting values                  |   |
| 8          | Recommended operating conditions |   |
| 9          | Static characteristics           | 5 |
| 10         | Dynamic characteristics          | 6 |
| 11         | Waveforms                        |   |
| 12         | Package outline                  | 0 |
| 13         | Revision history 1               |   |
| 14         | Legal information                | 2 |
| 14.1       | Data sheet status                | 2 |
| 14.2       | Definitions1                     | 2 |
| 14.3       | Disclaimers                      | 2 |
| 14.4       | Trademarks1                      | 3 |
| 15         | Contact information              | 3 |
| 16         | Contents                         | л |

<sup>©</sup> Nexperia B.V. 2017. All rights reserved